

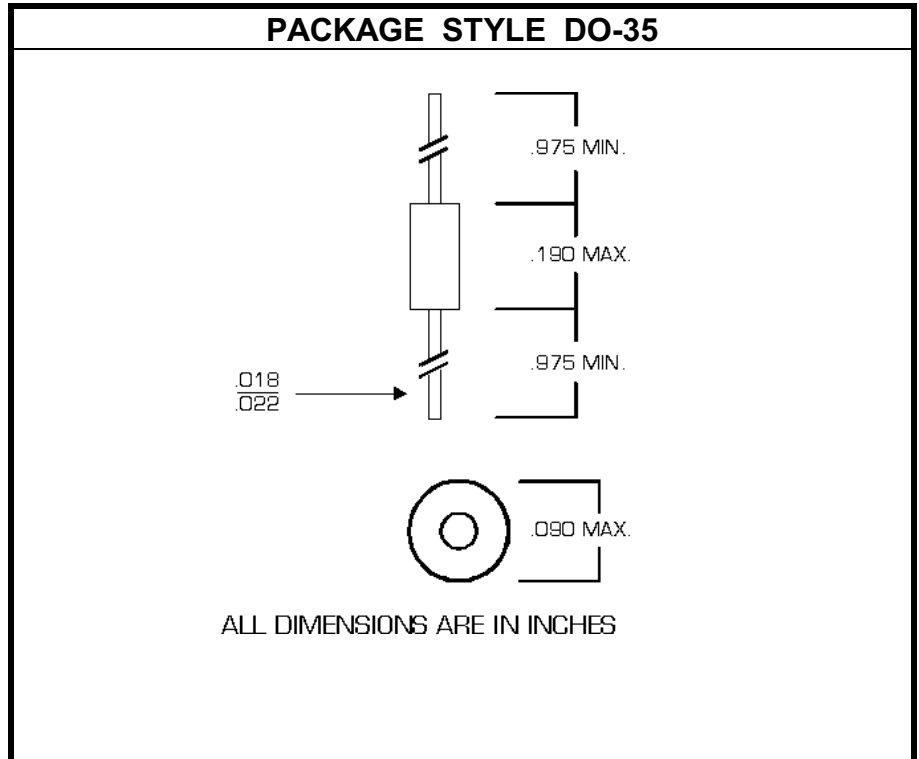
SCHOTTKY BARRIER DIODE

DESCRIPTION:

The **1N5711** is a Silicon Small Signal Schottky Diode for General Purpose UHF/VHF Detection and Pulse Applications. Color Band Indicates Cathode.

MAXIMUM RATINGS

I_F	15 mA
V_R	70 V
P_{DISS}	250 mW @ T _A = 25 °C
T_J	-65 °C to +200 °C
T_{STG}	-65 °C to +200 °C
θ_{JC}	700 °C/W


CHARACTERISTICS T_C = 25 °C

SYMBOL	TEST CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
V_{BR}	I _R = 10 μA	70			V
I_R	V _R = 50 V			200	nA
V_F	I _F = 1.0 mA I _F = 15 mA			0.41 1.0	v
C_T	V _R = 0 V f = 1.0 MHz			2.0	pF
τ	I _F = 5.0 mA			100	pS